ON Semiconductor

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Power Transistors

NPN Silicon DPAK For Surface Mount Applications

Designed for high-gain audio amplifier applications.

Features

- High DC Current Gain
- Low Collector-Emitter Saturation Voltage
- High Current-Gain Bandwidth Product
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|---|---------------|-----------|
| Collector-Base Voltage | V _{CB} | 50 | Vdc |
| Collector–Emitter Voltage | V _{CEO} | 50 | Vdc |
| Emitter-Base Voltage | | 5 | Vdc |
| Collector Current – Continuous | Collector Current – Continuous I _C | | Adc |
| Collector Current – Peak I _{CM} | | 3 | Adc |
| Base Current | Ι _Β | 0.4 | Adc |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | P _D | 15 0.1 | W W/°C |
| Total Device Dissipation @ T _A = 25°C* Derate above 25°C | P _D | 1.68 0.011 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -65 to +175 | °C |
| ESD – Human Body Model | HBM 3B | | V |
| ESD – Machine Model | MM | С | V |

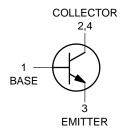
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

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SILICON POWER TRANSISTORS 2 AMPERES 50 VOLTS 15 WATTS





CASE 369C STYLE 1

MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week G = Pb-Free Device

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|--------------------|-------------------|-----------------------|
| NJVNJD2873T4G-VF01 | DPAK (Pb-Free) | 2,500 Units / Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|--|------------|------|
| Thermal Resistance Junction-to-Case Junction-to-Ambient (Note 1) | $egin{array}{c} {\sf R}_{	heta {\sf JC}} \ {\sf R}_{	heta {\sf JA}} \end{array}$ | 10 89.3 | °C/W |

^{1.} These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit | |
|--|-----------------------|-----------------|-----------------|------|--|
| OFF CHARACTERISTICS | | | | | |
| Collector–Emitter Sustaining Voltage (Note 2) $(I_C = 10 \text{ mAdc}, I_B = 0)$ | V _{CEO(sus)} | 50 | - | Vdc | |
| Collector Cutoff Current (V _{CB} = 50 Vdc, I _E = 0) | I _{CBO} | - | 100 | nAdc | |
| Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0) | I _{EBO} | - | 100 | nAdc | |
| ON CHARACTERISTICS | ON CHARACTERISTICS | | | | |
| DC Current Gain (Note 2) $ \begin{array}{l} (I_C = 0.5 \text{ A, V}_{CE} = 2 \text{ V}) \\ (I_C = 2 \text{ Adc, V}_{CE} = 2 \text{ Vdc}) \\ (I_C = 0.75 \text{ Adc, V}_{CE} = 1.6 \text{ Vdc, } -40^{\circ}\text{C} \leq T_J \leq 150^{\circ}\text{C}) \end{array} $ | h _{FE} | 120 40 80 | 360 - 360 | 1 | |
| Collector–Emitter Saturation Voltage (Note 2) (I _C = 1 A, I _B = 0.05 A) | V _{CE(sat)} | - | 0.3 | Vdc | |
| Base–Emitter Saturation Voltage (Note 2) (I _C = 1 A, I _B = 0.05 Adc) | V _{BE(sat)} | - | 1.2 | Vdc | |
| Base–Emitter On Voltage (Note 2) $ \begin{aligned} &(I_C=1 \text{ Adc, } V_{CE}=2 \text{ Vdc)} \\ &(I_C=0.75 \text{ Adc, } V_{CE}=1.6 \text{ Vdc, } -40^{\circ}\text{C} \leq T_J \leq 150^{\circ}\text{C}) \end{aligned} $ | V _{BE(on)} | - - | 1.2 0.95 | Vdc | |
| DYNAMIC CHARACTERISTICS | | | | | |
| Current–Gain – Bandwidth Product (Note 3) ($I_C = 100 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, $f_{test} = 10 \text{ MHz}$) | f _T | 65 | - | MHz | |
| Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz) | C _{ob} | - | 80 | pF | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \approx 2%.

3. $f_T = |h_{fe}| \bullet f_{test}$.

TYPICAL CHARACTERISTICS

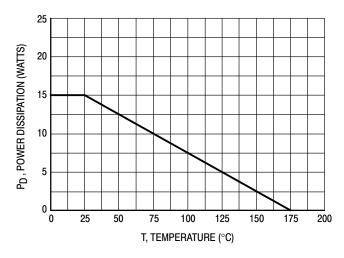


Figure 1. Power Derating

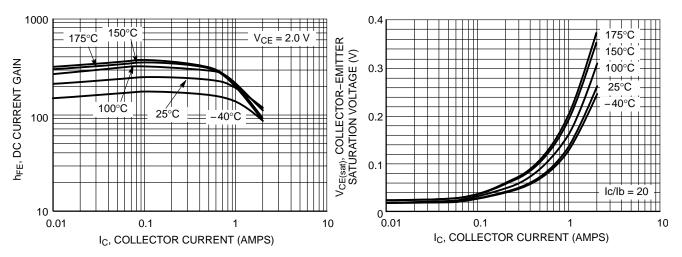


Figure 2. DC Current Gain

Figure 3. Collector-Emitter Saturation Voltage

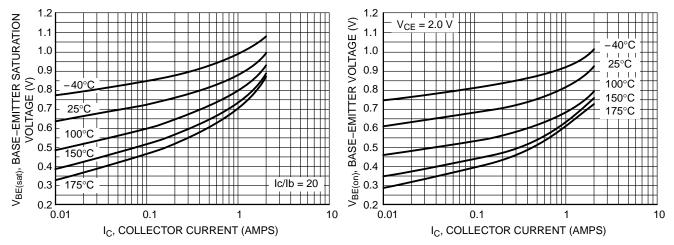
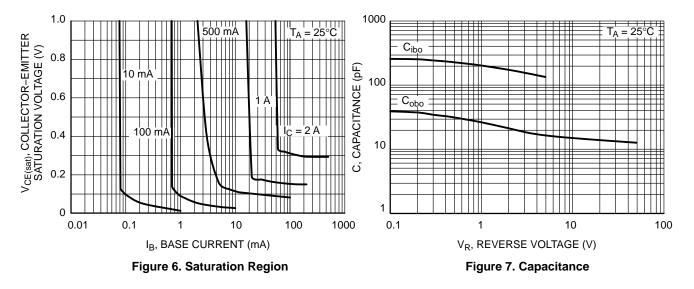


Figure 4. Base-Emitter Saturation Voltage

Figure 5. Base-Emitter Voltage



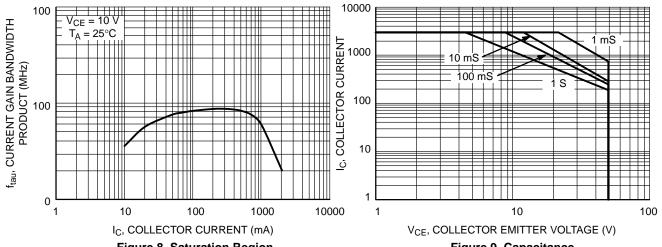


Figure 8. Saturation Region

Figure 9. Capacitance

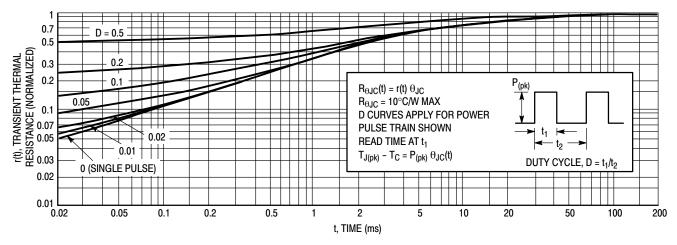
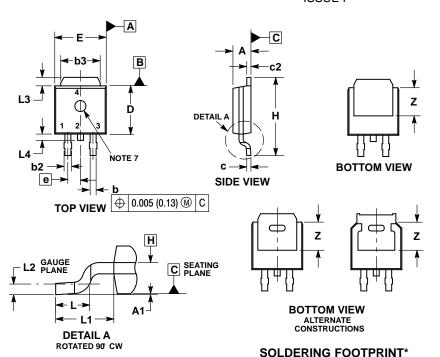


Figure 10. Thermal Response

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)

CASE 369C ISSUE F



NOTES

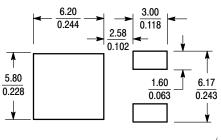
- 1. DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
 2. CONTROLLING DIMENSION: INCHES.
 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
- WENSIONS DS, LS allO E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
- DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
- 7. OPTIONAL MOLD FEATURE

| | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.086 | 0.094 | 2.18 | 2.38 |
| A1 | 0.000 | 0.005 | 0.00 | 0.13 |
| b | 0.025 | 0.035 | 0.63 | 0.89 |
| b2 | 0.028 | 0.045 | 0.72 | 1.14 |
| b3 | 0.180 | 0.215 | 4.57 | 5.46 |
| С | 0.018 | 0.024 | 0.46 | 0.61 |
| c2 | 0.018 | 0.024 | 0.46 | 0.61 |
| D | 0.235 | 0.245 | 5.97 | 6.22 |
| E | 0.250 | 0.265 | 6.35 | 6.73 |
| е | 0.090 BSC | | 2.29 BSC | |
| Н | 0.370 | 0.410 | 9.40 | 10.41 |
| L | 0.055 | 0.070 | 1.40 | 1.78 |
| L1 | 0.114 REF | | 2.90 REF | |
| L2 | 0.020 BSC | | 0.51 BSC | |
| L3 | 0.035 | 0.050 | 0.89 | 1.27 |
| L4 | | 0.040 | | 1.01 |
| Z | 0.155 | | 3.93 | |

STYLE 1:

- PIN 1. BASE 2. COLLECTOR

EMITTER COLLECTOR



SCALE 3:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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